NX3L2T66 Dual low-ohmic single-pole single-throw analog switch Rev. 7 – 8 February 2013 Product data sheet

1. General description

The NX3L2T66 is a dual low-ohmic single-pole single-throw analog switch. Each switch has two input/output terminals (nY and nZ) and an active HIGH enable input (nE). When pin nE is LOW, the analog switch is turned off.

Schmitt trigger action at the enable input (nE) makes the circuit tolerant to slower input rise and fall times. A low input voltage threshold allows pin nE to be driven by lower level logic signals without a significant increase in supply current I_{CC} . This makes it possible for the NX3L2T66 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation.

The NX3L2T66 allows signals with amplitude up to V_{CC} to be transmitted from nY to nZ; or from nZ to nY. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 4000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



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3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

Type number	Package	Package							
	Temperature range	Name	Description	Version					
NX3L2T66GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm	SOT833-1					
NX3L2T66GD	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $3 \times 2 \times 0.5$ mm	SOT996-2					
NX3L2T66GM	–40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body $1.6 \times 1.6 \times 0.5$ mm	SOT902-2					

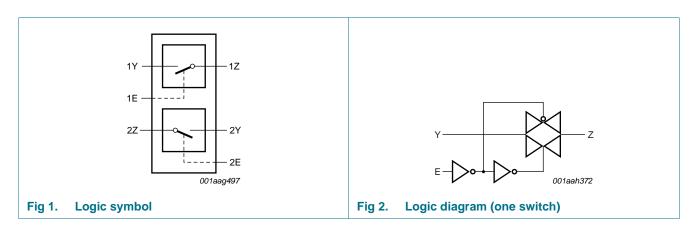
5. Marking

Table 2. Marking codes^[1]

Type number	Marking code
NX3L2T66GT	DOO
NX3L2T66GD	DOO
NX3L2T66GM	DOO

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram

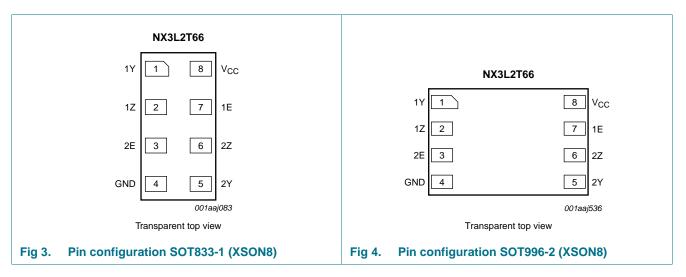


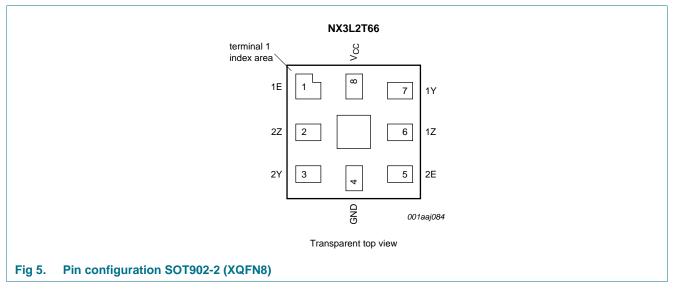
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7. Pinning information

7.1 Pinning





7.2 Pin description

Symbol	Pin		Description
-	SOT833-1 and SOT996-2	SOT902-2	
1Y, 2Y	1, 5	7, 3	independent input or output
1Z, 2Z	2, 6	6, 2	independent input or output
GND	4	4	ground (0 V)
1E, 2E	7, 3	1, 5	enable input (active HIGH)
V _{CC}	8	8	supply voltage

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8. Functional description

Table 4.Function table^[1]

Input nE	Switch
L	OFF-state
Н	ON-state

[1] H = HIGH voltage level;

L = LOW voltage level.

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	enable input nE	<u>[1]</u> –0.5	+4.6	V
V _{SW}	switch voltage		<u>[2]</u> –0.5	V _{CC} + 0.5	V
I _{IK}	input clamping current	$V_{I} < -0.5 V$	-50	-	mA
I _{SK}	switch clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±50	mA
I _{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	-	±350	mA
		V _{SW} > –0.5 V or V _{SW} < V _{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	<u>[3]</u> _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For XSON8 and XQFN8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.4	-	4.3	V
VI	input voltage	enable input nE	0	-	4.3	V
V _{SW}	switch voltage		<u>[1]</u> 0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.4 V to 4.3 V	[2] _	-	200	ns/V

[1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nY, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current will flow from terminal nY. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

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11. Static characteristics

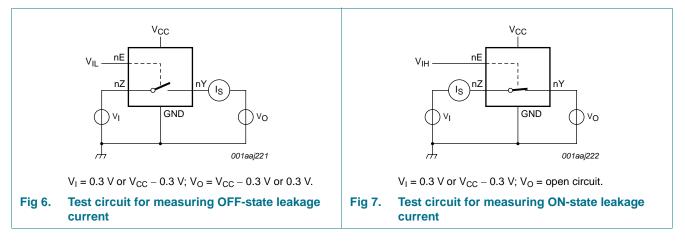
Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	amb = 25	°C	T _{amb} = -	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V _{IH}	HIGH-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	0.9	-	-	0.9	-	-	V
	input voltage	$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	0.9	-	-	0.9	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		V_{CC} = 2.7 V to 3.6 V	1.3	-	-	1.3	-	-	V
		V_{CC} = 3.6 V to 4.3 V	1.4	-	-	1.4	-	-	V
V _{IL}	LOW-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	-	0.3	-	0.3	0.3	V
	input voltage	V_{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V
		V_{CC} = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V
		V_{CC} = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V
I	input leakage current	enable input nE; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μA
I _{S(OFF)}	OFF-state	nY port; see <u>Figure 6</u>							
	leakage	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±10	-	±50	±500	nA
I _{S(ON)}	ON-state	nZ port; see <u>Figure 7</u>							
	leakage	$V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		$V_{CC} = 3.6 V$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	7000	nA
ΔI_{CC}	additional	V_{SW} = GND or V_{CC}							
	supply current	$V_1 = 2.6 V; V_{CC} = 4.3 V$	-	2.0	4.0	-	7	7	μA
		$V_1 = 2.6 V; V_{CC} = 3.6 V$	-	0.35	0.7	-	1	1	μA
		$V_{I} = 1.8 V; V_{CC} = 4.3 V$	-	7.0	10.0	-	15	15	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	2.5	4.0	-	5	5	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$	-	50	200	-	300	500	nA
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{\text{S}(\text{OFF})}$	OFF-state capacitance		-	35	-	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	110	-	-	-	-	pF

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11.1 Test circuits



11.2 ON resistance

Table 8.ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 9 to Figure 15.

Symbol	Parameter	ParameterConditions $T_{amb} = -40$ °C to +85 °C			-40 °C to 5 °C	Unit		
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA};$ see <u>Figure 8</u>						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		V _{CC} = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$	[2]					
		$V_{CC} = 1.4 V$	-	0.04	0.3	-	0.3	Ω
		V _{CC} = 1.65 V	-	0.04	0.2	-	0.3	Ω
		$V_{CC} = 2.3 V$	-	0.02	0.08	-	0.1	Ω
		$V_{CC} = 2.7 V$	-	0.02	0.075	-	0.1	Ω
		$V_{CC} = 4.3 V$	-	0.02	0.075	-	0.1	Ω

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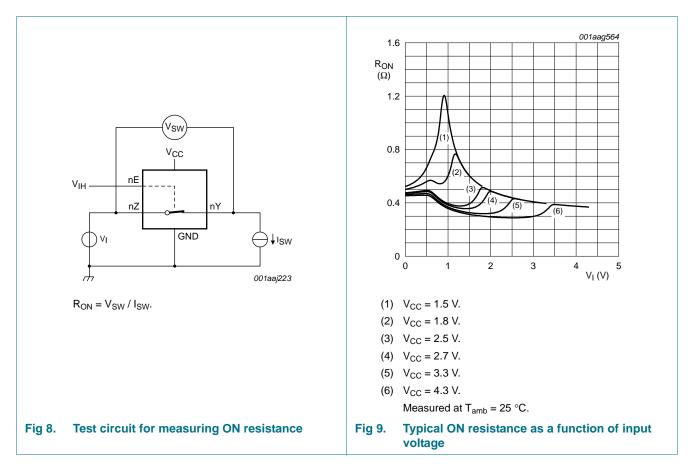
Symbol	Parameter	Conditions T _a		T _{amb} = -40 °C to +85 °C			T _{amb} = −40 °C to +125 °C		
			Min	Typ[1]	Max	Min	Max		
R _{ON(flat)} ON resistance	ON resistance (flatness)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$			'				
		$V_{CC} = 1.4 V$	-	1.0	3.3	-	3.6	Ω	
		V _{CC} = 1.65 V	-	0.5	1.2	-	1.3	Ω	
		$V_{CC} = 2.3 V$	-	0.15	0.3	-	0.35	Ω	
		$V_{CC} = 2.7 V$	-	0.13	0.3	-	0.35	Ω	
		$V_{CC} = 4.3 V$	-	0.2	0.4	-	0.45	Ω	

Table 8. **ON resistance** ... continued

[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

Measured at identical $V_{\mbox{CC}},$ temperature and input voltage. [2]

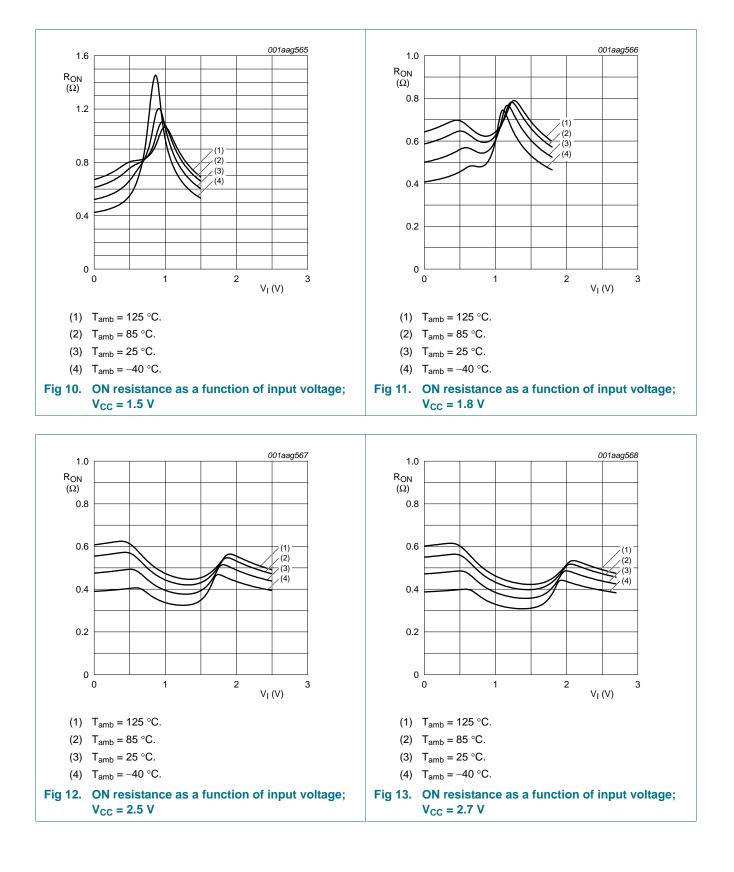
Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and [3] temperature.



11.3 ON resistance test circuit and graphs

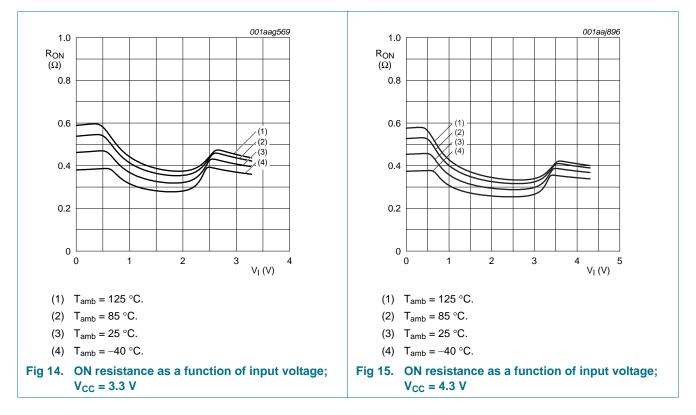
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12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Symbol Parameter Conditions		Ta	_{mb} = 25	°C	T _{amb} =	–40 °C to	+125 °C	Unit
			Min	Тур <u>^[1]</u>	Мах	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	nE to nZ or nY; see <u>Figure 16</u>							
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	35	49	-	53	57	ns
		V_{CC} = 1.65 V to 1.95 V	-	28	40	-	43	48	ns
		V_{CC} = 2.3 V to 2.7 V	-	20	30	-	32	35	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	18	28	-	30	32	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	18	28	-	30	32	ns
t _{dis}	disable time	nE to nZ or nY; see <u>Figure 16</u>							
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	32	70	-	80	90	ns
		V_{CC} = 1.65 V to 1.95 V	-	23	55	-	60	65	ns
		V_{CC} = 2.3 V to 2.7 V	-	14	25	-	30	35	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	11	20	-	25	30	ns
		V_{CC} = 3.6 V to 4.3 V	-	11	20	-	25	30	ns

[1] Typical values are measured at $T_{amb} = 25$ °C and $V_{CC} = 1.5$ V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

Dual low-ohmic single-pole single-throw analog switch

12.1 Waveform and test circuits

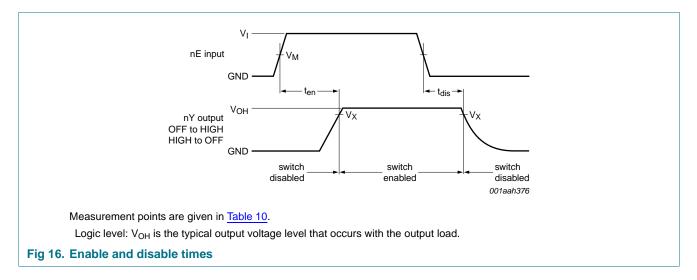


Table 10.Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

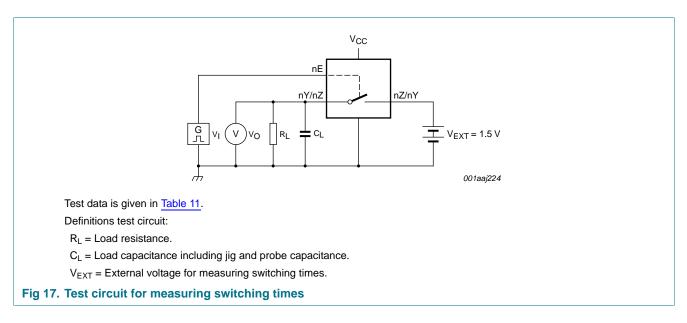


Table 11. Test data

Supply voltage	Input		Load	
V _{cc}	VI	t _r , t _f	CL	RL
1.4 V to 4.3 V	V _{CC}	\leq 2.5 ns	35 pF	50 Ω

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12.2 Additional dynamic characteristics

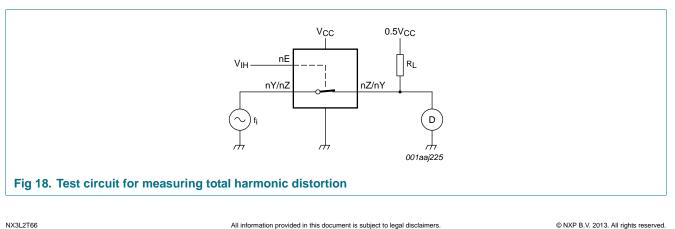
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_1 = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5 \text{ ns.}$

Symbol	Parameter	Conditions	T _{amb} = 25 °C			Unit	
				Min	Тур	Max	
THD	total harmonic distortion	$f_i = 20$ Hz to 20 kHz; $R_L = 32 \Omega$; see Figure 18	<u>[1]</u>		1		
		V _{CC} = 1.4 V; V _I = 1 V (p-p)		-	0.15	-	%
		V _{CC} = 1.65 V; V _I = 1.2 V (p-p)		-	0.10	-	%
		V _{CC} = 2.3 V; V _I = 1.5 V (p-p)		-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$		-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$		-	0.02	-	%
f _(-3dB)	–3 dB frequency response	$R_L = 50 \Omega$; see <u>Figure 19</u>	<u>[1]</u>				
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$		-	60	-	MHz
α_{iso}	isolation (OFF-state)	$f_i = 100 \text{ kHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 20}}{1000 \text{ kHz}}$	<u>[1]</u>				
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$		-	-90	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 21					
		$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$		-	0.2	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		-	0.2	-	V
Xtalk	crosstalk	between switches; $f_i = 100 \text{ kHz; } R_L = 50 \Omega$; see <u>Figure 22</u>	<u>[1]</u>				
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$		-	-90	-	dB
Q _{inj}	charge injection	$f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure } 23}{2}$					
		V _{CC} = 1.5 V		-	3	-	рС
		V _{CC} = 1.8 V		-	3	-	рС
		$V_{CC} = 2.5 V$		-	3	-	рС
		$V_{CC} = 3.3 V$		-	3	-	рС
		$V_{CC} = 4.3 V$		-	6	-	рС

[1] f_i is biased at 0.5V_{CC}.

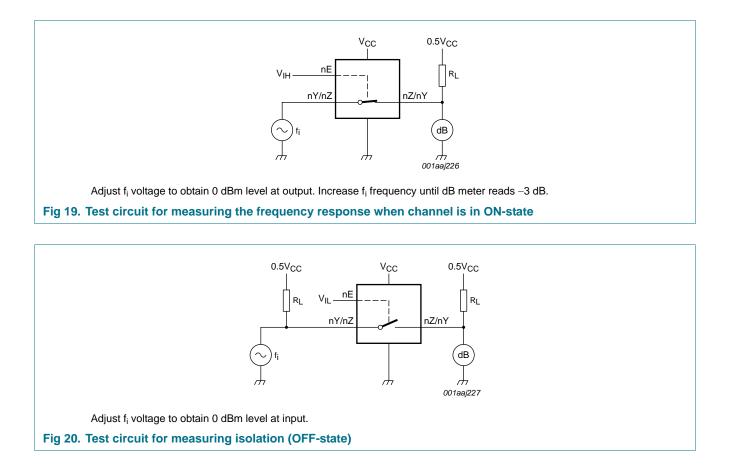
12.3 Test circuits



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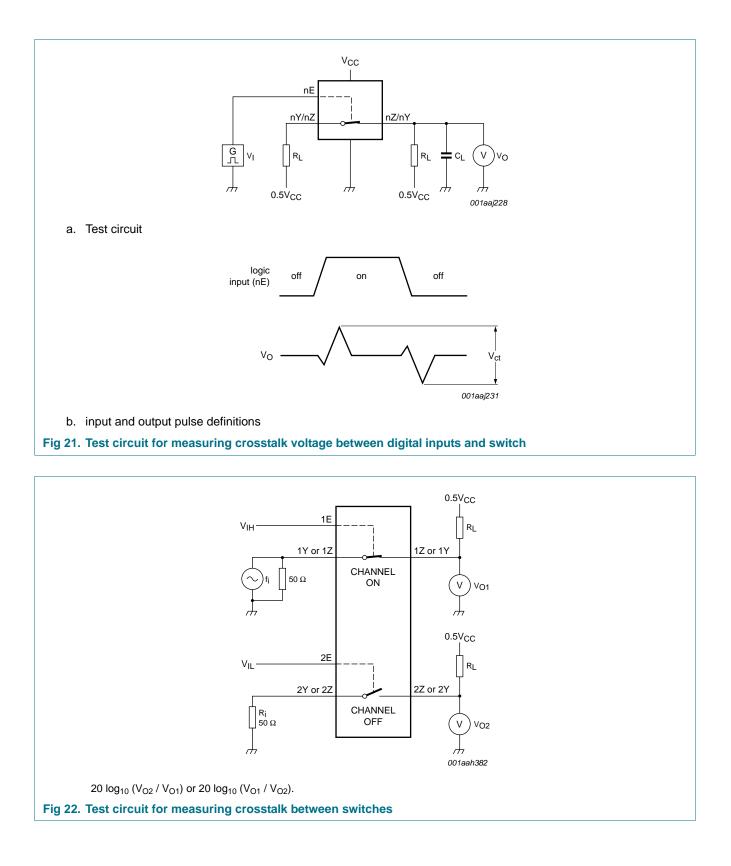
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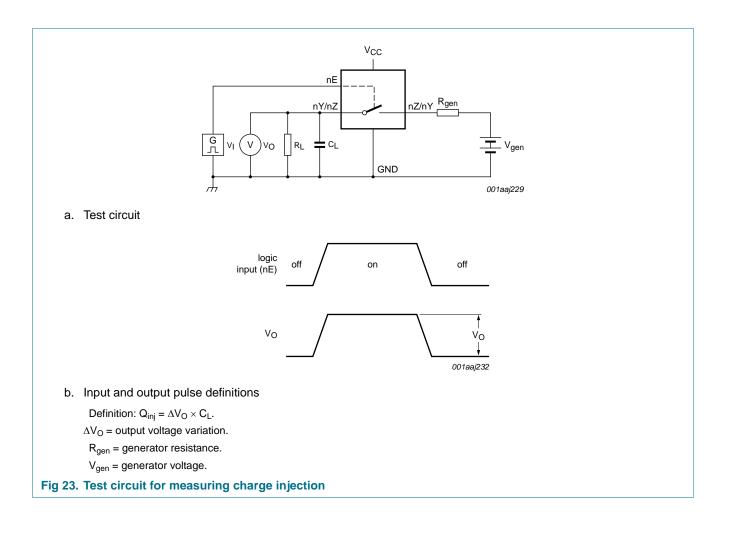
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NX3L2T66

Dual low-ohmic single-pole single-throw analog switch



Dual low-ohmic single-pole single-throw analog switch

13. Package outline

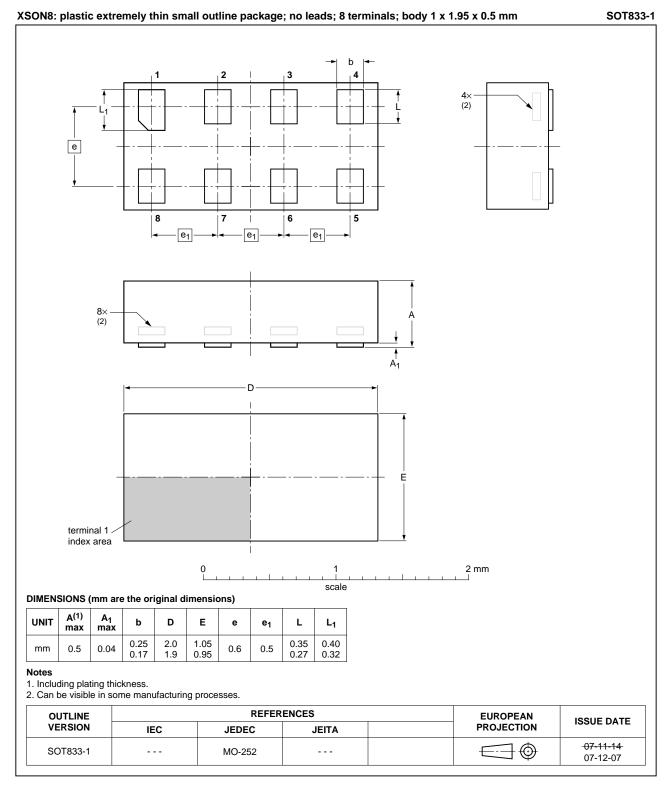
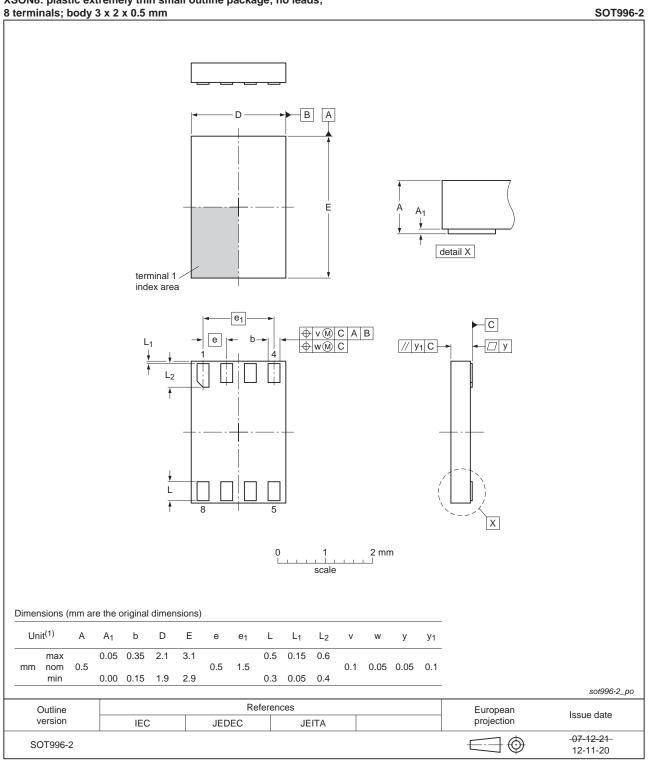


Fig 24. Package outline SOT833-1 (XSON8)

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Dual low-ohmic single-pole single-throw analog switch

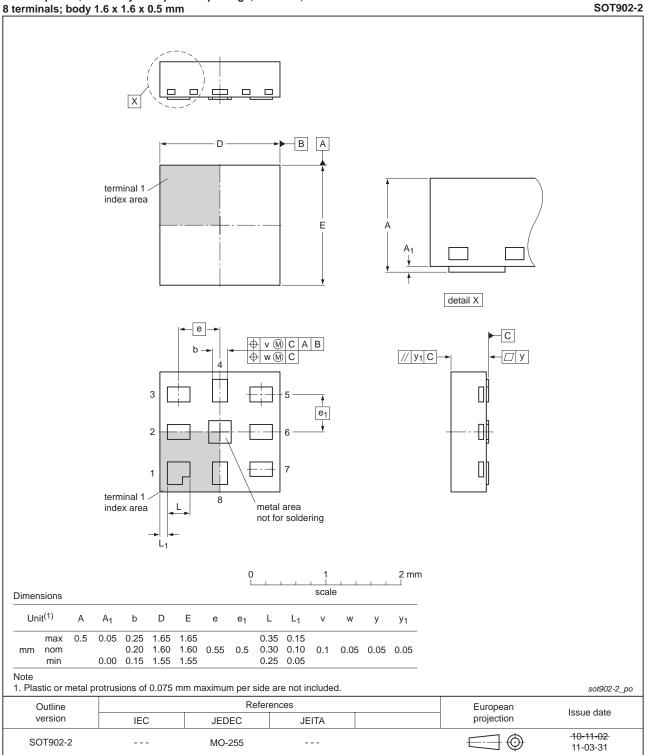


XSON8: plastic extremely thin small outline package; no leads;

Fig 25. Package outline SOT996-2 (XSON8)

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XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals: body 1.6 x 1.6 x 0.5 mm

Fig 26. Package outline SOT902-2 (XQFN8)

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14. Abbreviations

AcronymDescriptionCDMCharged Device ModelCMOSComplementary Metal Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body ModelMMMachine ModelPDAPersonal Digital Assistant	Table 13. Abbreviations			
CMOSComplementary Metal Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body ModelMMMachine Model	Acronym	Description		
ESDElectroStatic DischargeHBMHuman Body ModelMMMachine Model	CDM	Charged Device Model		
HBM Human Body Model MM Machine Model	CMOS	Complementary Metal Oxide Semiconductor		
MM Machine Model	ESD	ElectroStatic Discharge		
	HBM	Human Body Model		
PDA Personal Digital Assistant	MM	Machine Model		
	PDA	Personal Digital Assistant		

15. Revision history

Table 14. Revisior	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L2T66 v.7	20130208	Product data sheet	-	NX3L2T66 v.6
Modifications:	 For type null 	mber NX3L2T66GD XSON	8U has changed to XSO	N8.
NX3L2T66 v.6	20120606	Product data sheet	-	NX3L2T66 v.5
NX3L2T66 v.5	20111107	Product data sheet	-	NX3L2T66 v.4
NX3L2T66 v.4	20101229	Product data sheet	-	NX3L2T66 v.3
NX3L2T66 v.3	20090828	Product data sheet	-	NX3L2T66 v.2
NX3L2T66 v.2	20090420	Product data sheet	-	NX3L2T66 v.1
NX3L2T66 v.1	20081204	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Dual low-ohmic single-pole single-throw analog switch

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